

Plastic Silicon Infrared Phototransistor

QSE113, QSE114

Description

The QSE113/114 is a silicon phototransistor encapsulated in a wide angle, infrared transparent, black plastic sidelooker package.

Features

- NPN Silicon Phototransistor
- Package Type: Sidelooker
- Medium Wide Reception Angle, 50°
- Package Material and Color: Black Epoxy
- Matched Emitter: QEE113
- Daylight Filter
- High Sensitivity
- Blue Dot Marking on the Top Side
- This is a Pb-Free Device

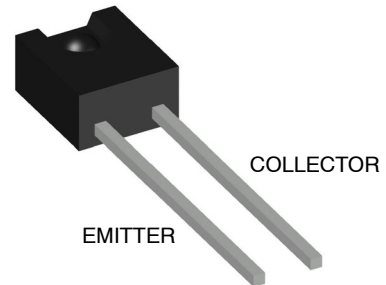
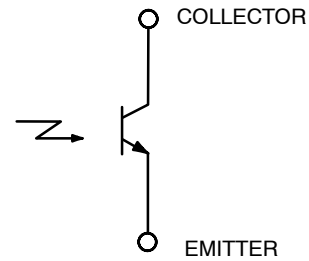
ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
T _{OPR}	Operating Temperature	-40 to +100	°C
T _{STG}	Storage Temperature	-40 to +100	°C
T _{SOL-I}	Soldering Temperature (Iron) (Note 2), (Note 3), (Note 4)	240 for 5 s	°C
T _{SOL-F}	Soldering Temperature (Flow) (Note 2), (Note 3)	260 for 10 s	°C
V _{CE}	Collector-Emitter Voltage	30	V
V _{EC}	Emitter-Collector Voltage	5	V
P _D	Power Dissipation (Note 1)	100	mW

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Derate power dissipation linearly 1.33 mW/°C above 25°C.
2. RMA flux is recommended.
3. Methanol or isopropyl alcohols are recommended as cleaning agents.
4. Soldering iron 1/16" (1.6 mm) minimum from housing.

SCHEMATIC



SIDELOOKER DETECTOR
CASE 100CJ

ORDERING INFORMATION

Device	Package	Shipping
QSE113	SIDELOOKER DETECTOR (Pb-Free)	500 / Bulk Bag
QSE114		

QSE113, QSE114

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
λ_{PS}	Peak Sensitivity Wavelength		–	880	–	nm
Θ	Reception Angle		–	± 25	–	°
I_{CEO}	Collector–Emitter Dark Current	$V_{CE} = 10\text{ V}$, $E_e = 0$	–	–	100	nA
BV_{CEO}	Collector–Emitter Breakdown	$I_C = 1\text{ mA}$	30	–	–	V
BV_{ECO}	Emitter–Collector Breakdown	$I_E = 100\text{ }\mu\text{A}$	5	–	–	V
$I_{C(ON)}$	On–State Collector Current (Note 5) QSE113 QSE114	$E_e = 0.5\text{ mW/cm}^2$, $V_{CE} = 5\text{ V}$	0.25 1.00	– –	1.50 –	mA
$V_{CE(SAT)}$	Saturation Voltage (Note 5)	$E_e = 0.5\text{ mW/cm}^2$, $I_C = 0.1\text{ mA}$	–	–	0.4	V
t_r	Rise Time	$I_C = 1\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 100\text{ }\Omega$	–	8	–	μs
t_f	Fall Time		–	8	–	μs

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. $\lambda = 880\text{ nm}$ (AlGaAs).

TYPICAL PERFORMANCE CHARACTERISTICS

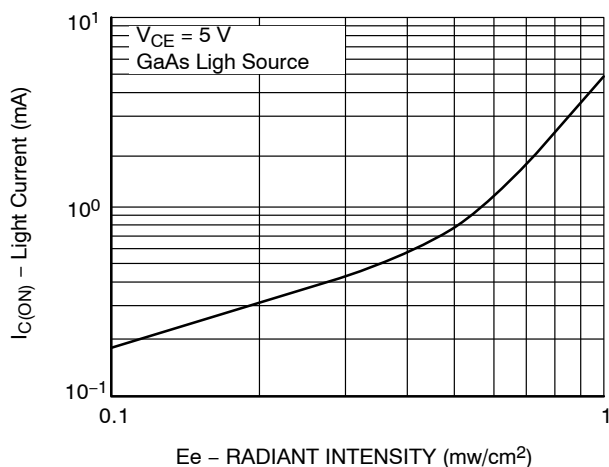


Figure 1. Light Current vs. Radiant Intensity

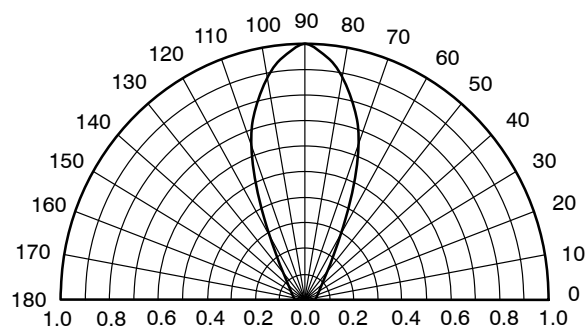


Figure 2. Angular Response Curve

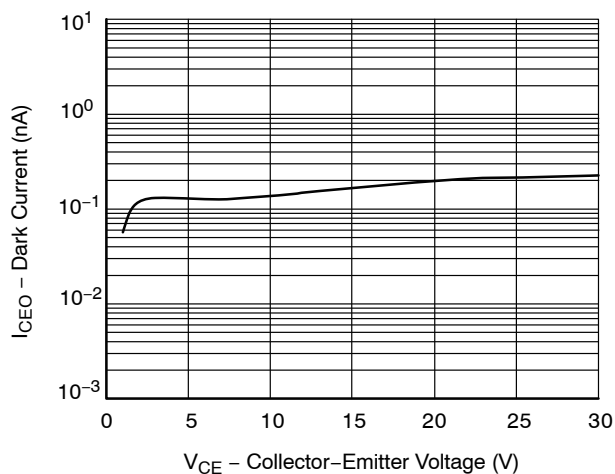


Figure 3. Dark Current vs. Collector - Emitter Voltage

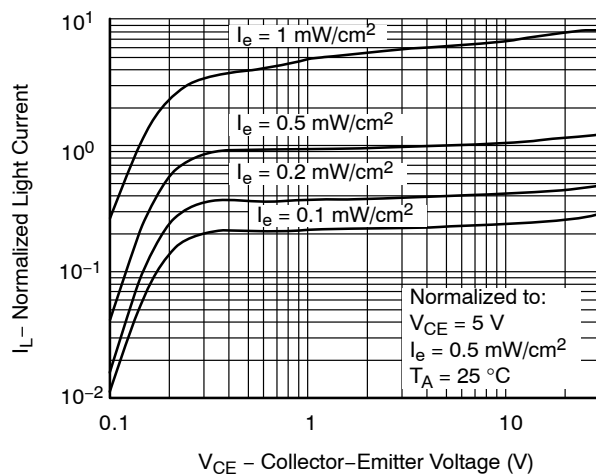


Figure 4. Light Current vs. Collector - Emitter Voltage

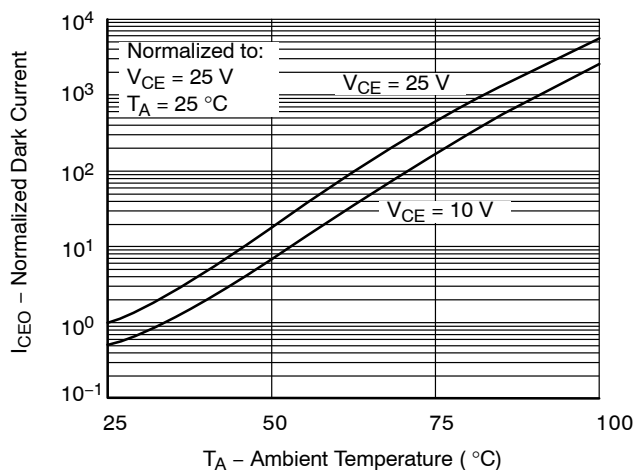
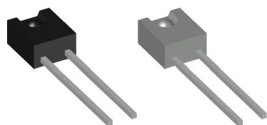
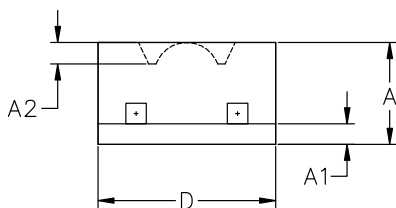


Figure 5. Dark Current vs. Ambient Temperature

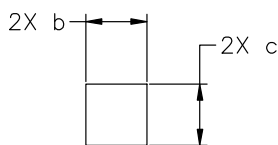


SIDELOOKER 4.44x5.08x2.54, 2.54P
CASE 100CJ
ISSUE A

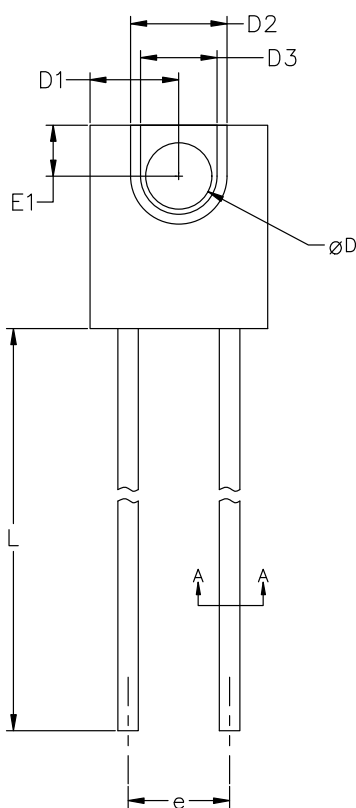
DATE 26 FEB 2024



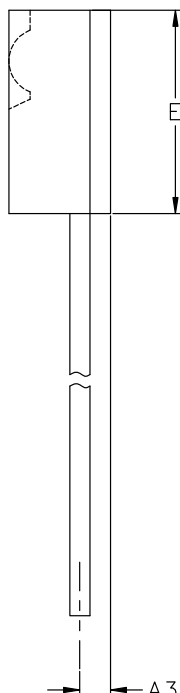
END VIEW



Section "A-A"
Scale 3:1



TOP VIEW



SIDE VIEW

DIMENSION (MILLIMETERS)			
	MIN	NOM	MAX
A	2.41	2.54	2.67
A1	0.38	0.51	0.64
A2	0.48	0.53	0.58
A3	0.64	0.76	0.89
b	0.51	0.57	0.61
c	0.51	0.57	0.61
D	4.32	4.44	4.57
D1	2.16	2.21	2.29
D2	2.29	2.41	2.54
D3	1.78	1.91	2.03
E	4.83	5.08	5.33
E1	1.14	1.27	1.40
e	2.41	2.54	2.67
øD	1.52	1.65	1.78
L	12.70	13.46	---

NOTES:

1. DIMENSIONING AND TOLERANCING AS PER ASMEY14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.

DOCUMENT NUMBER:	98AON13428G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	SIDELOOKER 4.44x5.08x2.54, 2.54P	PAGE 1 OF 1

onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at
www.onsemi.com/support/sales